

Afisarea articolelor 21-1(1) pentru cuvântul-cheie "Schottky barrier (SB)"

Analytical Drain Current Model of 1-D Ballistic Schottky-Barrier Transistors

Bejenari Igor^{1,2}, Schroter Michael², Claus Martin²

¹ Institute of the Electronic Engineering and Nanotechnologies "D. Ghitu" of the Academy of Sciences of Moldova,

IEEE Transactions on Electron Devices

9(64) / 2017 / ISSN - /ISSNe 0018-9383

Disponibil online 9 February, 2018. Descarcări-0. Vizualizări-702



Copyright © 2011-2024 Instrumentul Bibliometric Național.

Institutul de Dezvoltare a Societății Informaționale.

Actualizat: 25.06.2024, accesat: 25.06.2024

Disponibil: <https://ibn.idsi.md>

